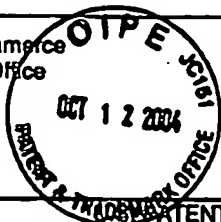


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(Rev. 8-88) Patent and Trademark Office

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INFORMATION DISCLOSURE CITATION
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Applicant: Nayfeh et al.

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Group: 1754

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Examiner

Michael Medner

Date Considered

12/16/2004

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